Active Doubler 7.5-22.5/15.0-45.0 GHz

Features

- +18 dBm Output Power
- -20 dBc Fundamental Leakage
- Lead-Free 3 mm 16-lead QFN Package
- 100% RF, DC and Output Power Testing
- RoHS* Compliant and 260°C Reflow Compatible

Description

The XX1000-QT is a 7.5-22.5/15.0-45.0 GHz SMD active doubler that delivers + 18 dBm of output power. The device combines an active doubler with an output buffer amplifier that delivers constant power over a range of input powers. The device has excellent rejection of the fundamental and harmonic products and requires a single positive bias supply.

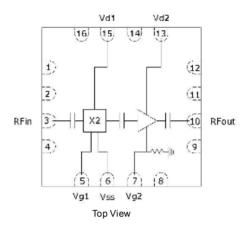
This device uses M/A-COM Technology Solutions' 0.15 GaAs pHEMT device model technology to ensure high reliability and uniformity. The device comes in a low-cost 3x3mm QFN Surface Mount Plastic Package offering excellent RF and thermal properties and is RoHS compliant. This device is well suited for Point-to-Point Radio, Microwave, LMDS, SATCOM and VSAT applications.

Ordering Information

| Part Number | Package | | |
|----------------|-------------------|--|--|
| XX1000-QT-0G00 | bulk quantity | | |
| XX1000-QT-0G0T | tape and reel | | |
| XX1000-QT-EV1 | evaluation module | | |

Rev. V1

Functional Block Diagram



Pin Configuration¹

| Pin No. | Function | Pin No. | Function | |
|---------|------------------|------------------|---------------|--|
| 3 | RF In | 13 | VD2 | |
| 5 | VG1 | 15 | VD1 | |
| 6 | VSS | 2,4,9,11 | Ground | |
| 7 | VG2 ¹ | 1,8,12,14, 16 | Not Connected | |
| 10 | RF Out | | | |

1. VG2 can be used for current regulating VD2 or VG2 can be set to GND withVD2 self-biasing at approximately 140mA.

Absolute Maximum Ratings²

| Parameter | Absolute Max. | | |
|----------------------------|--------------------------------------|--|--|
| Supply Voltage (Vd) | +6.0 VDC | | |
| Supply Voltage (Vss) | -6.0 VDC | | |
| Supply Current (Id) | 300 mA | | |
| Supply Current (Iss) | 60 mA | | |
| Gate Bias Voltage (Vg) | -0.4 VDC | | |
| Input Power (RF Pin) | +15.0 dBm | | |
| Storage Temperature (Tstg) | -65 °C to +165 °C | | |
| Operating Temperature (Ta) | -55 °C to MTTF Table ¹ | | |
| Channel Temperature (Tch) | MTTF Table ¹ | | |

2. Channel temperature directly affects a device's MTTF. Channel temperature should be kept as low as possible to maximize lifetime.

M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.

МЛСОМ



Active Doubler 7.5-22.5/15.0-45.0 GHz

Rev. V1

Electrical Specifications: 7.5-22.5 GHz Input Frequency (Ambient Temperature T=25°C)

| Parameter | Units | Min. | Тур. | Max. |
|------------------------------------------------------------------|-------|-------|------|-------|
| Output Frequency Range (fout) | GHz | 15.0 | - | 45.0 |
| Input Return Loss (S11) | dB | - | 15.0 | - |
| Output Return Loss (S22) | dB | - | 7.0 | - |
| Saturated Output Power (Psat) | dBm | - | +18 | - |
| RF Input Power (RF Pin) | dBm | -10.0 | - | +10.0 |
| Fundamental Leakage (fin) | dBc | - | 20 | - |
| Third Harmonic Leakage (3xfin) | dBc | - | 30 | - |
| Fourth Harmonic Leakage (4xfin) | dBc | - | 10 | - |
| Drain Bias Voltage (Vd1,2) | VDC | - | +5.0 | +5.5 |
| Gate Bias Voltage (Vg1) | VDC | -0.8 | -0.6 | -0.4 |
| Gate Bias Voltage (Vg2) | VDC | -1.2 | 0.0 | +0.1 |
| Supply Current (Id1,2) (Vd=5.0 V, Vg1=-0.6 V, Vg2=0.0 V Typical) | mA | - | 220 | 250 |
| Source Voltage (Vss) | VDC | -5.5 | -5.0 | -2.0 |
| Source Current (Iss) | mA | 25 | 50 | 60 |

Handling Procedures

Please observe the following precautions to avoid damage:

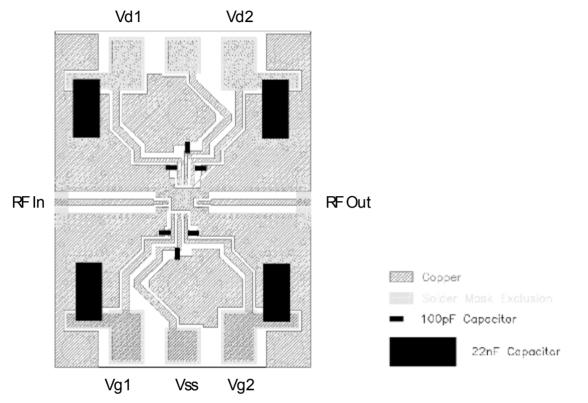
Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these class 2 devices.

M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.

Active Doubler 7.5-22.5/15.0-45.0 GHz





3

МАСОМ

Rev. V1

МАСОМ

Active Doubler 7.5-22.5/15.0-45.0 GHz

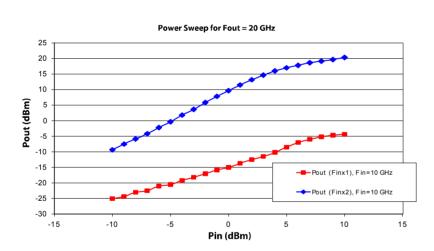
Fin

-10

-20

-30

Typical Performance Curves: Nominal Bias Conditions



15 17 19 21 23 25 27 29 31 33 35 37 39 41 43 45

Fout = 2xFin (GHz)

Measured results taken at room temperature in 40 GHz connectorized test fixture with no de-embedding.

2xFin, Pin=4dBm

2xFin, Pin=6dBm

-2xFin, Pin=8dBm

📥 2xFin, Pin=10dBm

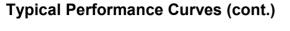
M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.

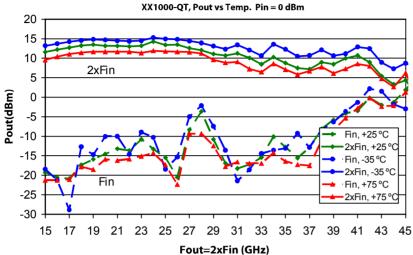
Rev. V1

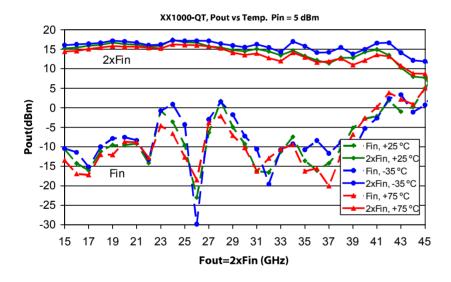


Active Doubler 7.5-22.5/15.0-45.0 GHz

Rev. V1







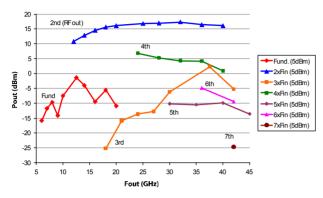
M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.



Rev. V1

Active Doubler 7.5-22.5/15.0-45.0 GHz

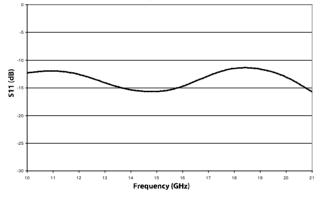
Typical Performance Curves (cont.)



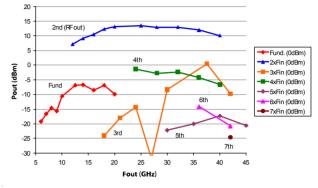
Harmonic Products, Pin = +5 dBm (Fin = 6 - 20 GHz)

* Measured on-wafer with pre-packaging.

XX1000-QT: Input Return Loss (dB)



Harmonic Products, Pin = +0 dBm (Fin = 6 - 20 GHz)



* Measured on-wafer with pre-packaging.

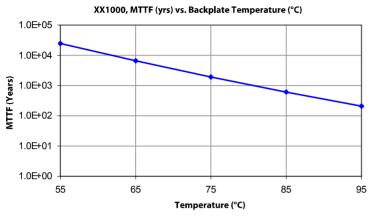
M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.

Active Doubler 7.5-22.5/15.0-45.0 GHz



Rev. V1

MTTF



MTTF is calculated from accelerated life-time data of single devices and assumes isothermal back-plate.

Bias Conditions: Vd1,2 = 5.0V, Id1,2 = 220 mA, Vss = -5.0V, Iss = 50 mA

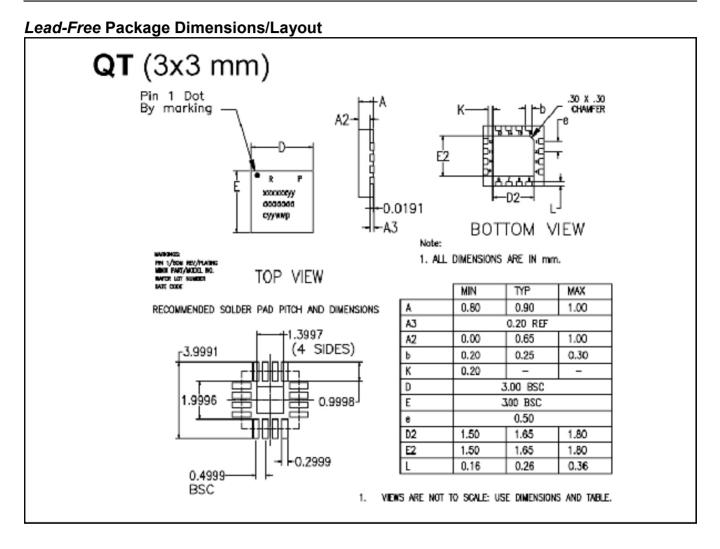
App Note [1] Biasing - It is recommended to separately bias each doubler stage with fixed voltages of Vd(1,2) =5.0V, Vss=-5.0V and Vg1=-0.6V. The typical DC currents are Id1=80mA, Id2=140mA and Iss=50mA. Vg2 can be used for active control biasing of Vd2, or it can be set to GND and Vd2 will self bias at approximately 140mA. Maximum output power is achieved with Vss=-5.0V and Iss=50mA but the device will operate with reduced bias to Vss=-2.0V and Iss=25mA. It is also recommended to use active biasing on Vd2 with Vg2 to keep the currents constant as the RF power and temperature vary; this gives the most reproducible results. Depending on the supply voltage available and the power dissipation constraints, the bias circuit may be a single transistor or a low power operational amplifier, with a low value resistor in series with the drain supply used to sense the current. The gate of the pHEMT is controlled to maintain correct drain current and thus drain voltage. The typical gate voltage for Vg2=-0.1V. Typically the gate is protected with Silicon diodes to limit the applied voltage. Also, make sure to sequence the applied voltage to ensure negative gate bias is available before applying the positive drain supply.

M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.

7

Active Doubler 7.5-22.5/15.0-45.0 GHz

Rev. V1



M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.

MACOM

Active Doubler 7.5-22.5/15.0-45.0 GHz



Rev. V1

M/A-COM Technology Solutions Inc. All rights reserved.

Information in this document is provided in connection with M/A-COM Technology Solutions Inc ("MACOM") products. These materials are provided by MACOM as a service to its customers and may be used for informational purposes only. Except as provided in MACOM's Terms and Conditions of Sale for such products or in any separate agreement related to this document, MACOM assumes no liability whatsoever. MACOM assumes no responsibility for errors or omissions in these materials. MACOM may make changes to specifications and product descriptions at any time, without notice. MACOM makes no commitment to update the information and shall have no responsibility whatsoever for conflicts or incompatibilities arising from future changes to its specifications and product descriptions. No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document.

THESE MATERIALS ARE PROVIDED "AS IS" WITHOUT WARRANTY OF ANY KIND, EITHER EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, CONSEQUENTIAL OR INCIDENTAL DAMAGES, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT. MACOM FURTHER DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. MACOM SHALL NOT BE LIABLE FOR ANY SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS, WHICH MAY RESULT FROM THE USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.

⁹

M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.